CTS21
CTS21E

Solid tantalum MnO$_2$ capacitors
Hermetically sealed metal cases
Axial leads
For power supplies and converters
Polarized

ELECTRICAL AND CLIMATIC CHARACTERISTICS

	CTS21	CTS21E
Detail specification	CECC 30201-040	CECC 30201-040
Operating temperature	−55℃ +125℃	−55℃ +125℃
Damp heat	56 days	56 days
Capacitance range	5,6μF ⇨ 330μF	22μF ⇨ 1000μF
Tolerance	±10% - ±20%	±10% - ±20%
Voltage range	6,3V ⇨ 50V	6,3V ⇨ 50V
Max. capacitance change −55℃	−10%	−10%
Max. capacitance change +85℃	+8%	+8%
Max. capacitance change +125℃	+12%	+12%
Maximum DF at +20℃	see table	see table
Maximum DF at −55℃	= 2 x lim20℃	= 2 x lim20℃
Maximum DF at +85℃	= 1,5 x lim20℃	= 1,5 x lim20℃
Maximum DF at +125℃	= 1,5 x lim20℃	= 1,5 x lim20℃
Max. leakage current at +20℃	see table	see table
Max. leakage current at +85℃	0,1 x $C_R U_R$	0,1 x $C_R U_R$
Max. leakage current at +125℃	0,125 x $C_R U_R$	0,125 x $C_R U_R$
Max. ESR at 100kHz +20℃	see table	see table
Max. ripple current 1kHz +20℃	see table	see table
Max. ripple current 100kHz +20℃	see table	see table
High surge current	1 million cycles	1 million cycles
Max. Reverse voltage at +20℃	15 % U_R	15 % U_R
Max. Reverse voltage at +85℃	5 % U_R	5 % U_R
Max. Reverse voltage at +125℃	1 % U_R	1 % U_R
Max. surge voltage at +85℃	1,3 x U_R	1,3 x U_R
Max. surge voltage at +125℃	1,3 x U_C	1,3 x U_C

DIMENSIONS (mm)

Case code	Dimensions with insulating sleeve			
	Lt max	L max	D max	d +10%/− 0,05
C	20,5	18,2	7,5	0,6
D	24,0	20,8	9,1	0,6

MARKING, PACKAGING, CONSTRUCTION:
see general characteristics

(*) 23mm for capacitors delivered on tape

HOW TO ORDER

Commercial description	Model		Case	Capacitance in μF	Tolerance in %	DC Voltage	Termination
	CTS21	CTS21E	D	22μF	20%	50V	H
EXXELIA PN	Model code		Case	Capacitance code	Tolerance code	DC Voltage code	Termination
	TS21	TS21E	D	226	M	050	A

	Expressed in pF with 3 digits: 2 digits for the value and the third for the multiplier	K = 10% M = 20%	Expressed in volt with 3 digits	**Commercial description** H = SnPb (No RoHS) - = Sn100% (RoHS)	**EXXELIA PN** A = SnPb (No RoHS) F = Sn100% (RoHS)
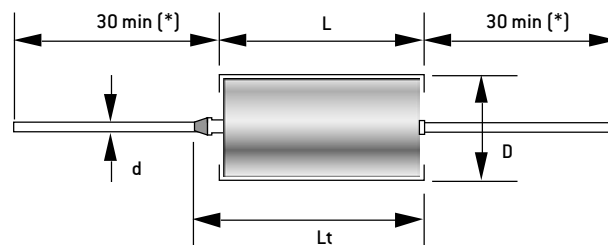
CTS21

(Standard range)

STANDARD RATINGS - ELECTRICAL CHARACTERISTICS

Capacitance 1kHz +20°C (µF)	Case (code)	Type	Max. I leak +20°C (µA)	Max. DF 1kHz +20°C (%)	Max. ESR 100kHz +20°C (mΩ)	Irms Max. 1kHz +20°C (A)	Irms Max. 100kHz +20°C (A)
Rated voltage (+85°C) 6,3 V (6 V for CTS21M) - Category voltage (+125°C) 4 V							
120	C	CTS21	7,6	8	70	2,5	3,2
150	C	CTS21	9,4	10	65	2	3,3
270	D	CTS21	17	10	50	3,4	4,1
330	D	CTS21	20,8	12	45	3,8	4,3
Rated voltage (+85°C) 10 V - Category voltage (+125°C) 6,3 V							
82	C	CTS21	8,2	8	85	1,8	2,9
100	C	CTS21	10	8	75	2,2	3
180	D	CTS21	18	8	60	3,4	3,7
220	D	CTS21	22	10	55	3,4	3,9
Rated voltage (+85°C) 16 V (15 V for CTS21M) - Category voltage (+125°C) 10 V							
56	C	CTS21	8,9	6	100	1,8	2,6
68	C	CTS21	10,8	6	95	2,2	2,7
120	D	CTS21	19,2	8	70	2,8	3,5
150	D	CTS21	24	8	65	3,1	3,6
Rated voltage (+85°C) 20 V - Category voltage (+125°C) 13 V							
39	C	CTS21	7,8	5	120	1,7	2,4
47	C	CTS21	9,4	6	110	1,8	2,5
82	D	CTS21	16,4	6	85	2,5	3,1
100	D	CTS21	20	8	75	2,5	3,3
Rated voltage (+85°C) 25 V - Category voltage (+125°C) 16 V							
27	C	CTS21	6,7	5	145	1,2	2,2
33	C	CTS21	8,2	5	130	1,4	2,3
56	D	CTS21	14	6	100	2,2	2,9
68	D	CTS21	17	6	95	2,4	3
Rated voltage (+85°C) 35 or 40 V (35 V for CTS21M) - Category voltage (+125°C) 23 or 25 V							
22	C	CTS21	7,7	4	160	1,5	2,1
27	D	CTS21	9,5	4	145	1,9	2,4
33	D	CTS21	11,6	5	130	1,9	2,5
39	D	CTS21	13,7	5	120	2	2,6
47	D	CTS21	16,5	5	110	2,2	2,7
Rated voltage (+85°C) 50 V - Category voltage (+125°C) 32 V							
5,6	C	CTS21	2,8	3	300	0,6	1,5
6,8	C	CTS21	3,4	3	275	0,7	1,6
8,2	C	CTS21	4,1	3	250	0,9	1,6
10	C	CTS21	5	3	230	1,1	1,7
12	C	CTS21	6	3	210	1,3	1,8
15	C	CTS21	7,5	3	190	1,4	1,9
18	C	CTS21	9	4	175	1,4	2,0
22	D	CTS21	11	4	160	1,7	2,3

(Extended range)

CTS21E

STANDARD RATINGS - ELECTRICAL CHARACTERISTICS

Capacitance 1kHz +20°C (µF)	Case (code)	Type	Max. I leak +20°C (µA)	Max. DF 1kHz +20°C (%)	Max. ESR 100kHz +20°C (mΩ)	Irms Max. 1kHz +20°C (A)	Irms Max. 100kHz +20°C (A)
Rated voltage (+85°C) 6,3 V - Category voltage (+125°C) 4 V							
330	C	CTS21E	20,8	12	45	2,4	3,9
390	C	CTS21E	24,6	12	40	2,6	4,1
470	C	CTS21E	29,6	14	40	2,6	4,2
680	D	CTS21E	42,8	18	35	4,0	5,2
820	D	CTS21E	51,7	18	30	4,0	5,2
1000	D	CTS21E	63	22	30	4,1	5,7
Rated voltage (+85°C) 10 V - Category voltage (+125°C) 6,3 V							
220	C	CTS21E	22	10	55	2,2	3,6
270	C	CTS21E	27	10	50	2,4	3,7
390	D	CTS21E	39	12	40	3,8	4,5
470	D	CTS21E	47	14	40	3,8	4,5
560	D	CTS21E	56	14	35	3,9	4,8
Rated voltage (+85°C) 16 V - Category voltage (+125°C) 10 V							
150	C	CTS21E	24	10	65	2,0	3,3
180	C	CTS21E	28,8	10	60	2,4	3,4
270	D	CTS21E	43,2	10	50	3,4	4,1
330	D	CTS21E	52,8	12	45	3,8	4,3
Rated voltage (+85°C) 20 V - Category voltage (+125°C) 13 V							
100	C	CTS21E	20	8	75	2,2	3,0
120	C	CTS21E	24	8	70	2,5	3,2
180	D	CTS21E	36	10	60	3,4	3,7
220	D	CTS21E	44	10	55	3,4	3,9
Rated voltage (+85°C) 25 V - Category voltage (+125°C) 16 V							
56	C	CTS21E	14	6	100	1,8	2,6
68	C	CTS21E	17	6	95	2,2	2,7
82	C	CTS21E	20,5	6	85	2,2	2,9
150	D	CTS21E	37,5	10	65	2,8	3,6
Rated voltage (+85°C) 35 or 40 V - Category voltage (+125°C) 23 or 25 V							
33	C	CTS21E	11,5	5	130	1,4	2,3
39	C	CTS21E	13,6	5	120	1,7	2,4
47	C	CTS21E	16,4	6	110	1,8	2,5
56	D	CTS21E	19,6	6	100	2,2	2,9
68	D	CTS21E	23,8	6	95	2,4	3,0
82	D	CTS21E	28,7	6	85	2,5	3,1
100	D	CTS21E	35	8	75	2,5	3,3
120	D	CTS21E	42	8	70	2,8	3,5
Rated voltage (+85°C) 50 V - Category voltage (+125°C) 32 V							
22	C	CTS21E	11	4	160	1,5	2,1
27	C	CTS21E	13,5	5	145	1,5	2,2
33	D	CTS21E	16,5	5	130	1,9	2,5
39	D	CTS21E	19,5	5	120	2,0	2,6
47	D	CTS21E	23,5	6	110	2,2	2,7
56	D	CTS21E	28	6	100	2,2	2,9
68	D	CTS21E	34	6	95	2,4	3,0
Rated voltage (+85°C) 63 V - Category voltage (+125°C) 40 V							
47*	D	CTS21E	29,6	10	110	2,2	2,7

* out of CECC range

Electrical characteristics

CAPACITANCE

The capacitance is defined by a rated value (C_R, indicated on the capacitor) and a tolerance (generally ±20%).

The capacitance is measured for most of the types at a 100Hz frequency (1 kHz for CTS21 - CTS21E - CTC21 - CTC21E) under a 0,1 to 1 V_{AC} voltage and a 2,1 to 2,5 V bias.
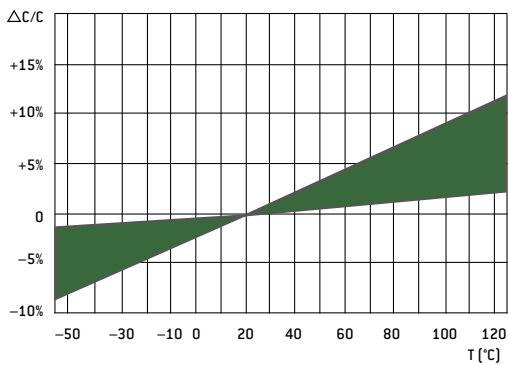At room temperature, it must be in the range defined by the rated value and the tolerance.
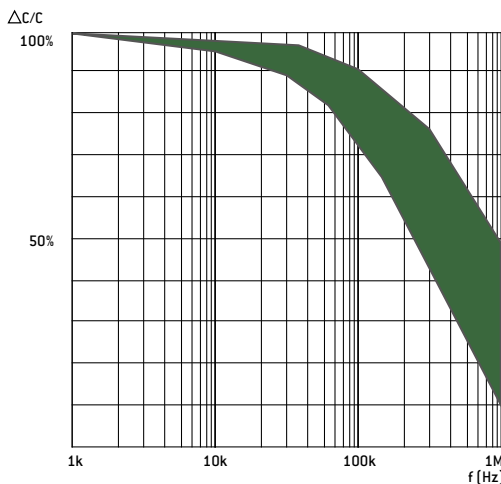
Capacitance change vs applied DC voltage: negligeable

CAPACITANCE CHANGE VS FREQUENCY: STANDARD TYPES
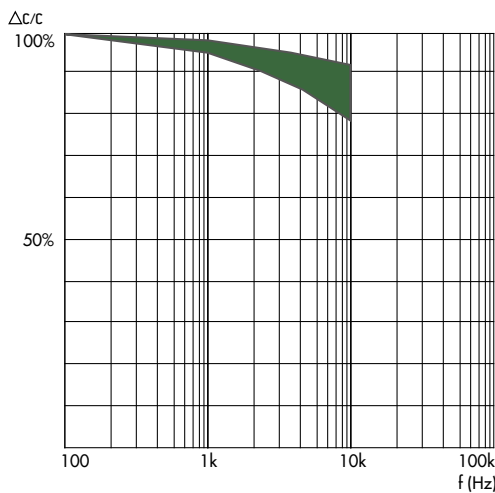
CAPACITANCE CHANGE VS TEMPERATURE: STANDARD TYPES

CAPACITANCE CHANGE VS FREQUENCY: CTC21 AND CTS21

CAPACITANCE CHANGE VS TEMPERATURE: CTC21 AND CTS21
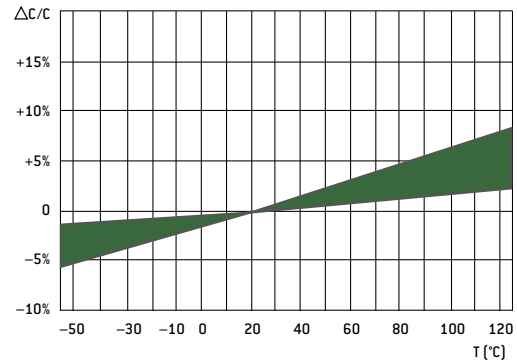
See typical curves below . Maximum changes are given, for each type, on the data sheets.

TOLERANCE (ON RATED CAPACITANCE)

It defines, with the rated capacitance, the range in which the capacitance value must be at room temperature

e.g.: Rated capacitance: 100μF
Tolerance: 20%
The measured capacitance must be between:
100 - (20% of 100) = 80 and 100 + (20% of 100) = 120
The standard tolerance for tantalum capacitors is 20%.
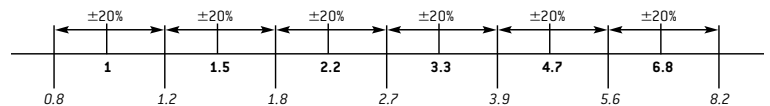
DIRECT DC VOLTAGE

The rated voltage (U_R), indicated on the capacitor, is the maximum DC voltage which can be applied continuously between −55℃ and +85℃.

For the types which can be used up to 125℃, the voltage must be derated between +85℃ and +125℃ according to the following curve.
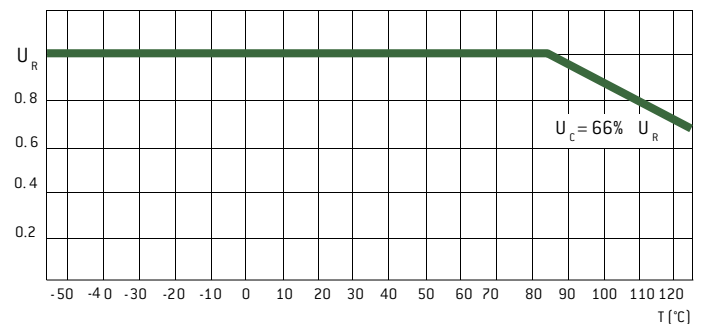
The category voltage (U_C) is consequently the maximum DC voltage which can be applied continuously at +125℃.

The surge voltage is the maximum voltage which can be applied for short periods.

It is given for each type in the data sheet and is generally equal to 1,3 times U_R between −55℃ and +85℃ and 1,3 times U_C at +125℃.

Tests are performed with charging periods of 30 seconds, through a 1000 Ω resistor, and discharging periods of 5 min 30 s. 1000 cycles are done.

Electrical characteristics

REVERSE VOLTAGE

This characteristic is not guaranteed for all types (see data sheets).

MAXIMUM REVERSE VOLTAGE IS GENERALLY:

- 0,15 times U$_R$ at +20℃
- 0,05 times U$_R$ at +85℃
- 0,01 times U$_R$ at +125℃

TESTS ARE PERFORMED WITH THE FOLLOWING CONDITIONS:

125 hours under Reverse voltage followed by 125 hours under direct voltage.

LEAKAGE CURRENT

Leakage current is the residual current which flows through the capacitor after the charging time, under rated voltage. It is measured after a time not exceeding 5 minutes and is given in μA.

It is equivalent to the insulation resistance of the capacitor and it must be as low as possible.

Maximum leakage current is a function of capacitance and rated voltage values and is given, for each type, in the data sheets.

AT 20℃, THE LIMIT IS GENERALLY:

Lc Max. (μA) = 0,01 x C$_R$ x U$_R$ with C$_R$ in μF and U$_R$ in V.

LEAKAGE CURRENT CHANGE VS APPLIED VOLTAGE
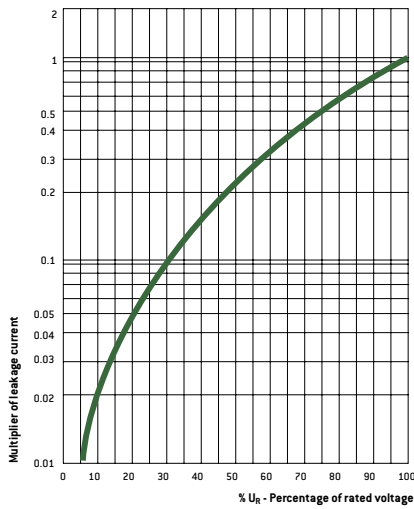
LEAKAGE CURRENT CHANGE VS TEMPERATURE
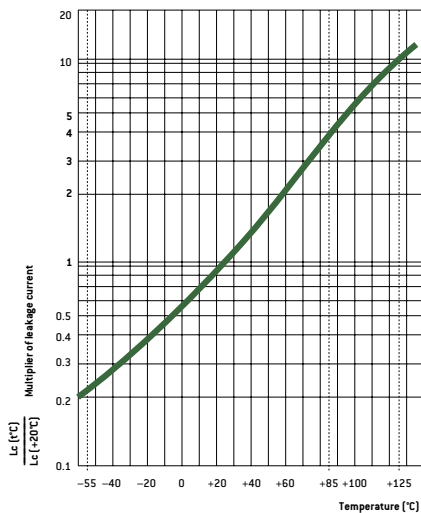
DISSIPATION FACTOR

Dissipation factor is generally measured at the same time as the capacitance (at 100Hz or 1kHz depending on the model), with the same conditions. It is a function of the series resistance of the capacitor and the capacitance at low frequency.
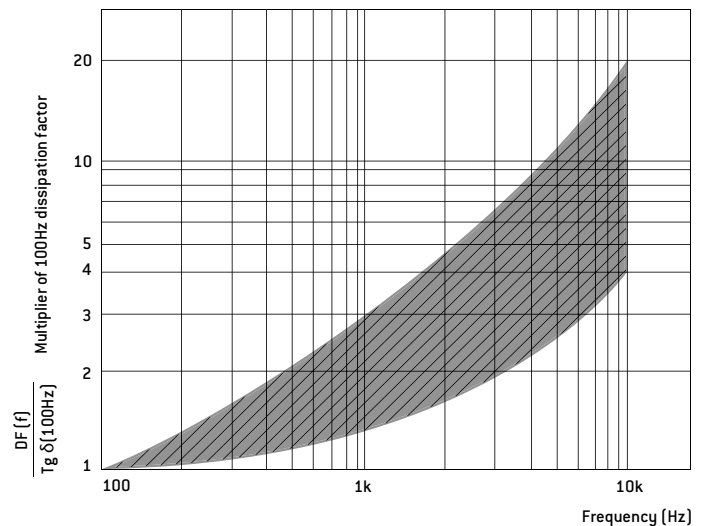
$$DF = ESR \times C \times 2\pi f$$

At low frequency, the series resistance is the sum of an ohmic part (leads, contacts, MnO$_2$) and the dielectric losses.
Dissipation factor is given in % and maximum limits are given for each type in the data sheets.
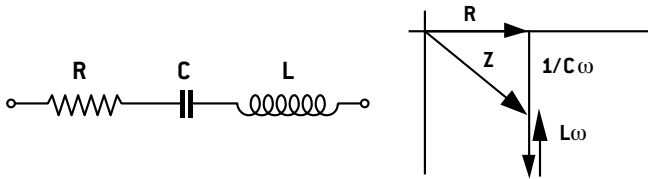
DISSIPATION FACTOR CHANGE VS TEMPERATURE
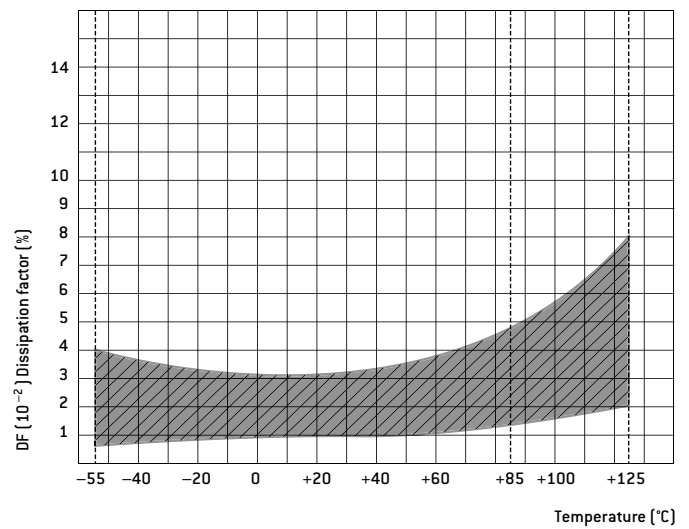
DISSIPATION FACTOR CHANGE VS FREQUENCY

Electrical characteristics

EQUIVALENT SERIES RESISTANCE OR IMPEDANCE

Equivalent circuit of a capacitor

R: equivalent series resistance of the capacitor (leads,contacts, MnO_2, dielectric losses)

L: inductance mainly due to the leads

C: capacitance

Equivalent Series Resistance for

CTS21	CTC21	CTC4	CTS41ESR	CTC42	CTP21
CTS21E	CTC21E	CTC4 RSE		CTC42E	CTP42

For these types which are specially designed to be used in power supplies and converters, a maximum ESR is given at a frequency of 100kHz or 500 kHz. Parameters such output ripple voltage and ripple current capability are directly a function of the ESR value.

Maximum ESR: see data sheets.

Impedance (for standard products)

For the others types, a maximum limit is given for the impedance. The formula for impedance is:

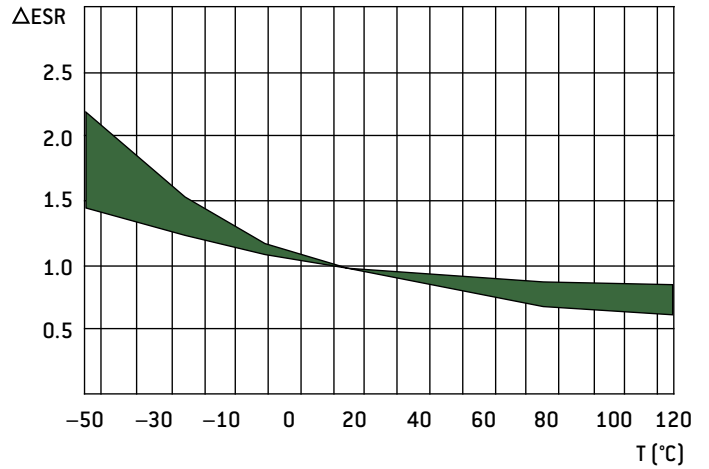$$Z = \sqrt{R^2 + (L\omega - 1/C\omega)^2}$$

Examples of impedance curves vs frequency are given in the following pages.
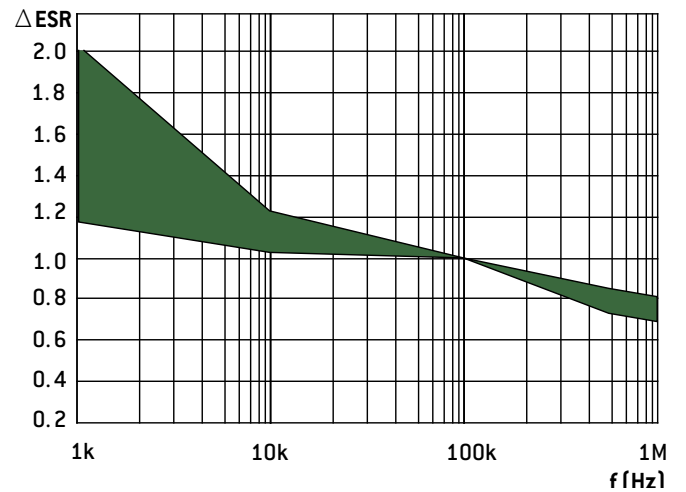
It can be seen that:

- at low frequencies, impedance is a function of capacitance
- at high frequencies, impedance is a function of inductance
- at medium frequencies, it is a function of the ESR

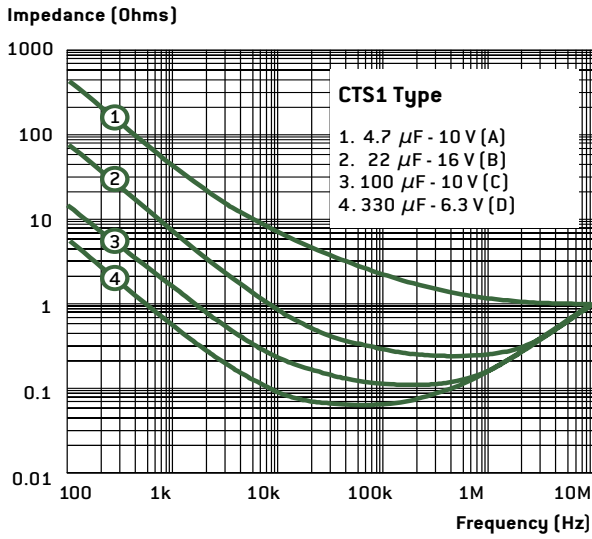Maximum impedance: see data sheets.

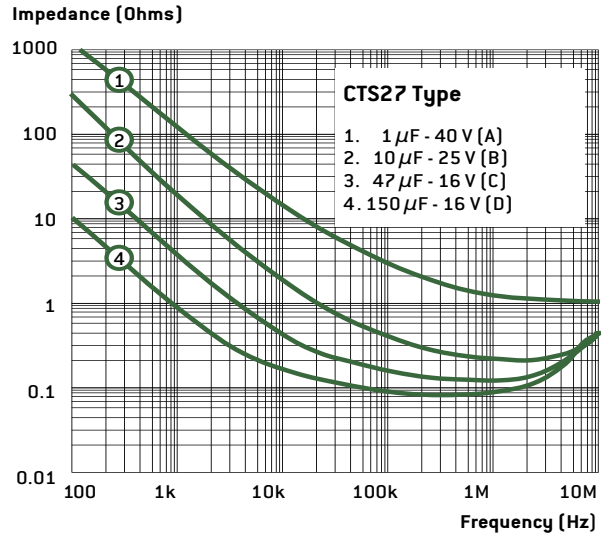**ESR CHANGE VS TEMPERATURE**

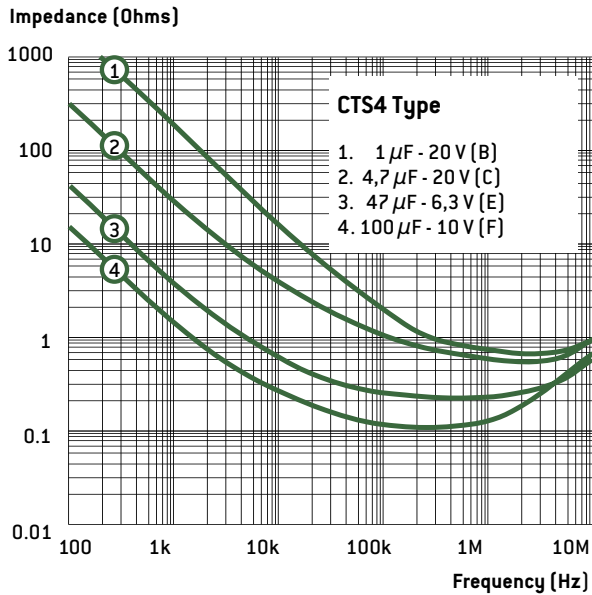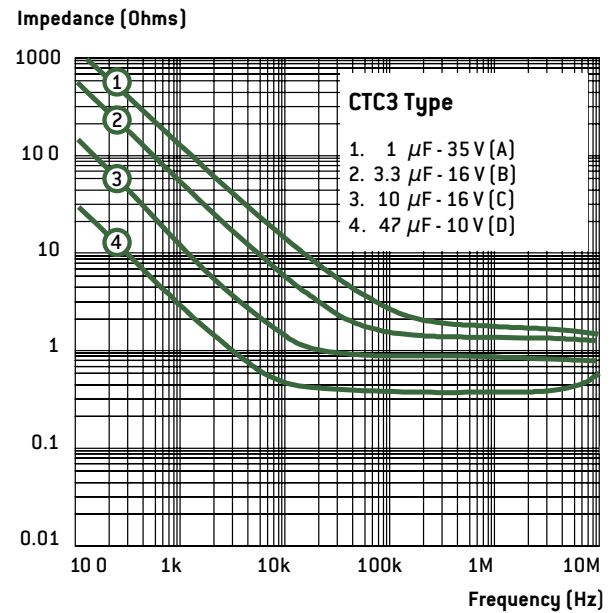**ESR CHANGE VS FREQUENCY**
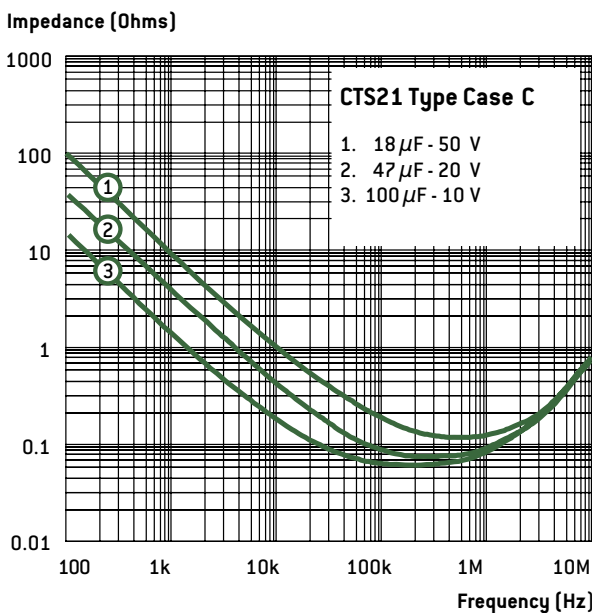
Electrical characteristics

CTS1 TYPE

Impedance (Ohms)

CTS1 Type

1. 4.7 µF - 10 V (A)
2. 22 µF - 16 V (B)
3. 100 µF - 10 V (C)
4. 330 µF - 6.3 V (D)

CTS27 TYPE

Impedance (Ohms)

CTS27 Type

1. 1 µF - 40 V (A)
2. 10 µF - 25 V (B)
3. 47 µF - 16 V (C)
4. 150 µF - 16 V (D)

CTS4 TYPE

Impedance (Ohms)

CTS4 Type

1. 1 µF - 20 V (B)
2. 4,7 µF - 20 V (C)
3. 47 µF - 6,3 V (E)
4. 100 µF - 10 V (F)

CTC3 TYPE

Impedance (Ohms)

CTC3 Type

1. 1 µF - 35 V (A)
2. 3.3 µF - 16 V (B)
3. 10 µF - 16 V (C)
4. 47 µF - 10 V (D)

CTS21 TYPE CASE C

Impedance (Ohms)

CTS21 Type Case C

1. 18 µF - 50 V
2. 47 µF - 20 V
3. 100 µF - 10 V

CTS21 TYPE CASE D

Impedance (Ohms)

CTS21 Type Case D

1. 22 µF - 50 V
2. 47 µF - 40 V
3. 100 µF - 20 V
4. 220 µF - 10 V
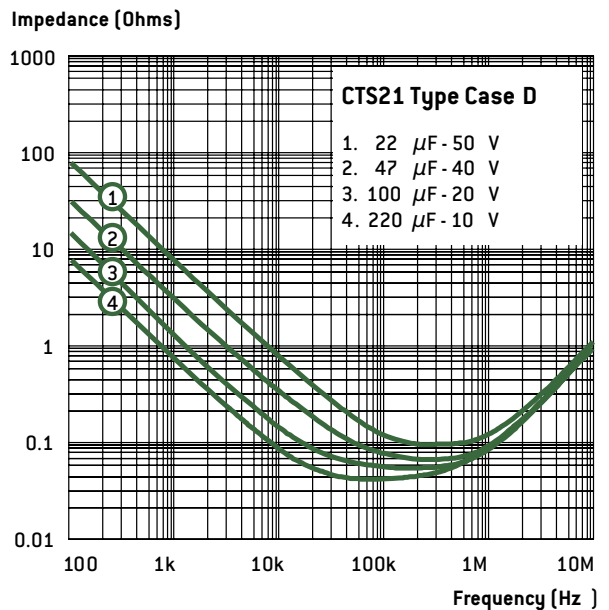
Electrical characteristics

CTS21E TYPE CASE C

Impedance (Ohms)

CTS21E Type Case C
1. 22 μF - 50 V
2. 47 μF - 40 V
3. 100 μF - 20 V
4. 220 μF - 10 V

Frequency (Hz)

CTS21E TYPE CASE D

Impedance (Ohms)

CTS21E Type Case D
1. 68 μF - 50 V
2. 100 μF - 40 V
3. 220 μF - 20 V
4. 560 μF - 10 V

Frequency (Hz)

CTC21 TYPE CASE C

Impedance (Ohms)

CTC21 Type Case C
1. 10 μF - 63 V
2. 22 μF - 40 V
3. 68 μF - 16 V
4. 150 μF - 6.3 V

Frequency (Hz)

CTC21 TYPE CASE D

Impedance (Ohms)

CTC21 Type Case D
1. 22 μF - 63 V
2. 47 μF - 40 V
3. 220 μF - 10 V

Frequency (Hz)

CTC21E TYPE CASE C

Impedance (Ohms)

CTC21E Type Case C
1. 10 μF - 100 V
2. 33 μF - 40 V
3. 100 μF - 25 V
4. 330 μF - 6.3 V

Frequency (Hz)

CTC21E TYPE CASE D

Impedance (Ohms)

CTC21E Type Case D
1. 22 μF - 100 V
2. 68 μF - 40 V
3. 220 μF - 20 V
4. 680 μF - 6.3 V

Frequency (Hz)

Electrical characteristics

MAXIMUM RIPPLE CURRENT - MAXIMUM RIPPLE VOLTAGE

The maximum value of the ripple current, or ripple voltage which can be applied to the capacitor is only limited by the thermal effect. Indeed, as the electrolyte is in this case a solid semi-conductor, there is no damage and physical change in the structure when a ripple current is flowing through it.

On the other hand, as the series resistance is not zero, there will be a heating which is proportional to the ESR and to the square of ripple current ($P = ESR \times Irms^2$)
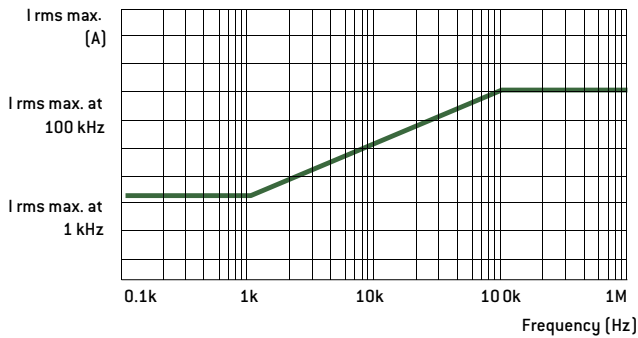
Types

|					
CTS21	CTC21	CTC4	CTS41 RSE	CTC42	SMT47
CTS21E	CTC21E	CTC4 RSE		CTC42E	

For these products, for which a maximum ESR is given, the maximum ripple current is also given in the data sheets. This value has been calculated with the maximum ESR values and a maximum dissipated power per case size.

As the ESR changes in frequency, maximum ripple currents are given for two frequencies (1kHz and 100kHz). For other frequencies, apply the rule given by the curve below.
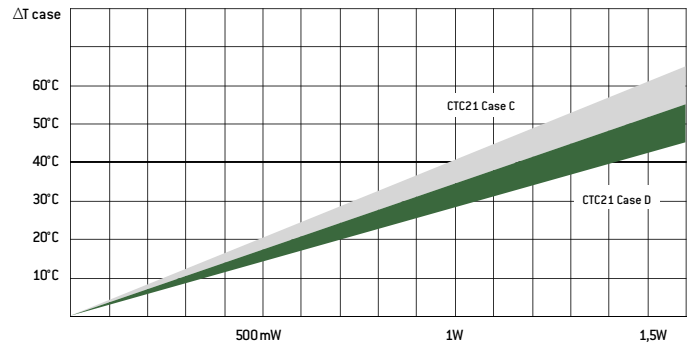
COEFFICIENT APPLY TO THE MAXIMUM RIPPLE CURRENT VS TEMPERATURE

As there is heating due to the ripple current, it is also necessary to derate the maximum ripple current when the room temperature is higher than 20℃:
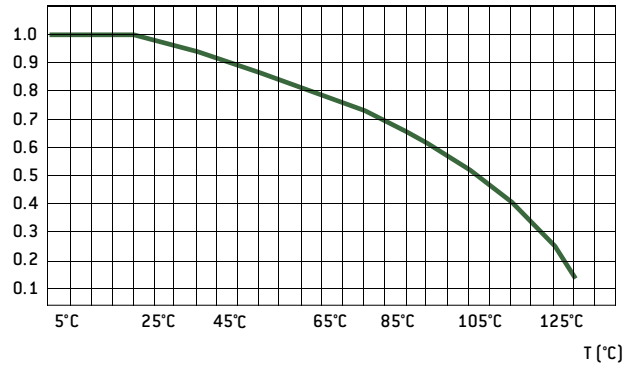
TYPICAL HEATING OF THE CASE VS DISIPATED POWER

Electrical characteristics

OTHERS TYPES

The same rule will be used to calculate the maximum ripple voltage:

$$\text{Irms Max.} = \sqrt{(\text{Pmax/ESR max})}$$

MAXIMUM DISSIPATED POWER WILL BE CHOSEN AS FOLLOW:

Metal cases (CTS1, CTS13, CTS23, CTS33, …)
- case A : 0,090 W
- case B : 0,100 W
- case C : 0,125 W
- case D : 0,180 W

Plastic cases (CTS27)
- case A : 0,080 W
- case B : 0,090 W
- case C : 0,100 W
- case D : 0,125 W

SMD cases (CTC3, CTC3E, …)
- case A : 0,075 W
- case B : 0,085 W
- case C : 0,110 W
- case D : 0,150 W
- case S : 0,060 W
- case T : 0,070 W
- case U : 0,090 W
- case V : 0,0125 W

These values should be derated at elevated temperature as follows

at +85℃: 0,9
at +125℃: 0,4

For maximum values of ESR, it will be possible to use the maximum impedance value given at 100kHz or to measure the ESR of capacitors.

Maximum ripple voltage can be calculated with the value of maximum ripple current and the following formula

$$\text{Urms} = Z \, (\text{impedance}) \times \text{Irms}$$

NOTE FOR ALL TYPES

In addition to the requirements due to thermal effects, maximum ripple currents and voltages will be limited by the following parameters:

- the sum of DC voltage and positive peak of AC voltage must be less than maximum allowable direct voltage of the capacitor.

- the negative peak of AC voltage will not create a voltage exceeding maximum allowable Reverse voltage.

9 - CHARGE DISCHARGE / SURGE CURRENT

For standard types of solid tantalum capacitors, it is necessary to limit the surge current by placing a resistance in series with the capacitor. The value of this resistance will be calculated by using the rule of 3Ω per volt (IMax. = 0,33 A).

However, some more recent types can be used without any limit on the surge current; these types are registered with the reference «high surge current» (eg : CTS32, CTS23, CTS33, CTS21, CTS21E, CTS41, CTS41ESR, CTC4, CTC4 RSE, CTC21, CTC21E, CTC42, CTC42E, SMT47).
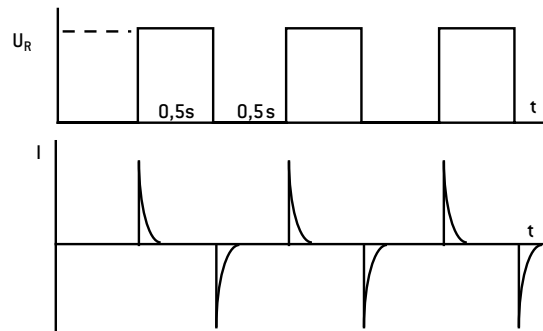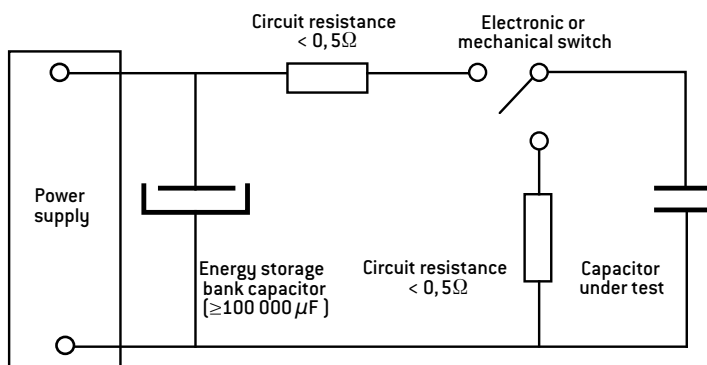
The high surge current test is performed to check that these capacitors can be used in low impedance circuits, and to make sure of their capability to withstand high surge currents.

The test being performed under rated voltage with a maximum 0,5 Ω circuit resistance, the peak surge current will be a minimum equal to Ip = U_R / 0,5 (if the ESR of the capacitor is considered as negligible).

e.g.: high surge current test performed on a CTS21 100μF-20 V (ESR=75mΩ, negligible compared to 0,5Ω) Surge current = 20/0.5 = 40 A during a few tens of μs.

Depending upon the types, this test can be 100% performed or on a sampling basis, during 3 to 5 cycles. During periodic tests, 1 million cycles are performed.

General characteristics

CLIMACTIC CHARACTERISTICS

1- CLIMATIC CATEGORY

Climatic category defines the temperature range over which the capacitor can be used continuously, and also the number of days for the damp heat test (this test is performed periodically at 40℃ with a 93% moisture rate).

Note: for types with a climatic range of −55℃ to +125℃, it is necessary to derate the voltage for temperatures higher than 85℃ (see page 84).

2- THERMAL SHOCKS - RAPID CHANGES OF TEMPERATURE

This test is performed to check that the capacitors can withstand sudden temperature changes. The method which is used is the one with two chambers, one at −55℃, the other one at +85℃ or +125℃, depending upon the types. Five cycles are performed, with 30 min at low temperature and 30 min at high temperature, during the periodic tests or on 100% of the batch. Electrical characteristics are measured after this test.

3 - DAMP HEAT TEST

This test is performed during the periodical test, with the following conditions:

Temperature: 40℃	DC voltage: without
Humidity: 90 to 95%	Time: 21 or 56 days

Electrical characteristics are measured after this test.

MECHANICAL CHARACTERISTICS

1 - VIBRATIONS

This test is performed during the periodical test, with the following conditions:

Metal cases
- Method B4
- Frequency: 10 to 2000Hz
- Amplitude: 1,5 mm or 196 m/s²
- Time: 6 hours

Plastic cases: CTS4 or CTS41 Type

Same conditions, except:
- Amplitude 0,75 mm or 98 m/s²

Plastic cases: CTS27 Type

Same conditions, except:
- Frequency: 10 to 55Hz
- Amplitude: 1,5 mm or 98 m/s²

2 - SHOCKS

This test is performed just after the vibrations test, with the following conditions for all types:
- Acceleration: 981 m/s²
- Pulse width: 6 ms
- Shape: 1/2 sinewave
- Number of shocks: 3 for each of the 3 directions

RELIABILITY - LIFE TIME

1 - RELIABILITY

Reliability of a component can be defined as its probability to work without any failure, in defined conditions and during a fixed time.

Reliability is not therefore only a function of the component quality, but also of the application and environmental conditions.

The parameter which is the most commonly used for the reliability is the failure rate in time, generally expressed in % per 1000 hours.

1-1 ESTABLISHED FAILURE RATE CAPACITORS (CTS1M)

This types, equivalent to MIL types, can be supplied with a fixed failure rate. This failure rate is coded with the following letters:

> M = 1.0 % / 1000 h
> P = B = 0.1% / 1000 h
> R = C = 0.01% / 1000 h
> S = D = 0.001% / 1000 h

For EXXELIA, the rate is calculated by recording the failures during the burn-in and according to the Weibull method.

The desired failure rate code letter must be added just after the type reference (ie: CTS1MC = CTS1M with a failure rate of 0.01% / 1000 hours).

1-2 CALCULATION OF A COMPONENT FAILURE RATE USED IN AN EQUIPMENT

The calculation method on the next page uses parameters which are given by the CNET (Centre National d'Étude des Télécommunications) in its Reliability Data Book (RDF 1993).

The failure rate is calculated with parameters which are function of the capacitor (capacitance, case type, approvals, high surge current test) and others ones which are representative of application conditions (voltage, temperature, resistance in series, environmental conditions).

Example: CTS21E 150μF-25 V used under 12 volts, at 40℃, without serie resistance, in a satellite in orbit:

$\pi_t = 1,2$ $\pi_V = 1,38$ $\pi_R = 1$ $\pi_B = 1$
$\pi_C = 1,8$ $\pi_E = 0,5$ $\pi_q = 1$

$\lambda = 4 \times 1,2 \times 1,38 \times 1 \times 1 \times 1,8 \times 0,5 \times 1 .10^{-9}/h$
$= 6.10^{-9}/h = 0,0006$ % defect/1000 hours

2 - LIFE TIME

There is no known damaging mechanism in time for solid tantalum capacitors; that is why it is difficult to give a precise life time.

However, life tests at 85℃ under rated voltage and 125℃ under derated voltage are periodically performed.

In addition, during qualification programs for new types, life test at 85℃ and 125℃ have been performed during 10000 hours and no significant parameter change have been observed.
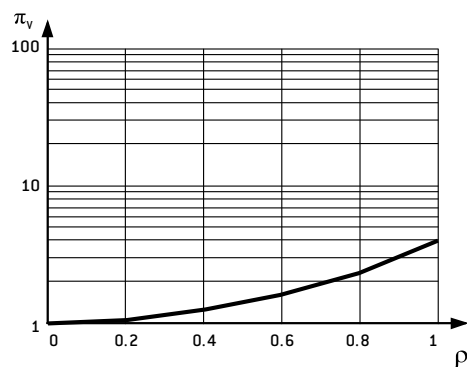
General characteristics

π_t = TEMPERATURE INFLUENCE
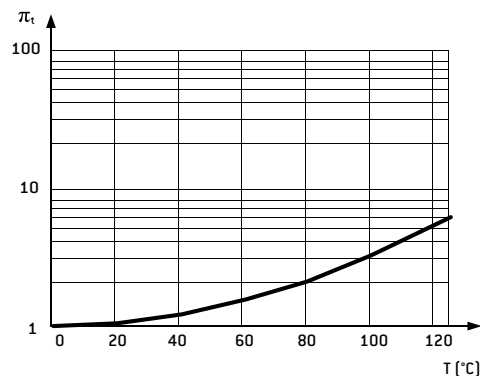
Formula: $\pi_t = \exp\left[1{,}8.\left(t/tm\right)^2\right]$

with:
t = using temperature
tm = maximum temperature
Curve for tm = 125°C

π_V = INFLUENCE OF APPLIED VOLTAGE VS RATED VOLTAGE

Formula: $\pi_v = \exp\left[\left(\rho/0{,}85\right)^2\right]$

$$\rho = \frac{\text{peak voltage}}{\text{rated voltage}}$$

Curve $\pi_v = f(\rho)$

π_R = INFLUENCE OF CIRCUIT RESISTOR IN SERIE

V = using voltage

R = circuit resistance between capacitor and power supply

1. Types with high surge current test: $\pi_R = 1$

2. Others types: π_R = function of R/V in /V

R/V ≥ 3	$\pi_R = 1$	R/V = 0,6	$\pi_R = 6$
R/V = 2	$\pi_R = 1{,}5$	R/V = 0,4	$\pi_R = 9$
R/V = 1	$\pi_R = 3$	R/V = 0,2	$\pi_R = 12$
R/V = 0,8	$\pi_R = 4{,}5$	R/V = 0,1	$\pi_R = 15$

π_E = INFLUENCE OF APPLICATION

Satellite in orbit	$\pi_E = 0{,}5$
Ground; stationary; protected	$\pi_E = 1$
Ground; stationary; non protected	$\pi_E = 2{,}5$
Ground; mobile; soft conditions	$\pi_E = 4$
Aircraft; soft conditions	$\pi_E = 4$
Ship; soft conditions	$\pi_E = 4$
Ground; mobile; hard conditions	$\pi_E = 5{,}5$
Ship; hard conditions	$\pi_E = 7$
Aircraft; hard conditions	$\pi_E = 10$
Satellite launching	$\pi_E = 12$

π_B = INFLUENCE OF CASE TYPE

Metal case	$\pi_B = 1$
Molded case	$\pi_B = 3$
Dipped	$\pi_B = 5$

π_C = INFLUENCE OF CAPACITANCE

0,1μF	$\pi_C = 0{,}75$
150μF	$\pi_C = 1{,}8$
330μF	$\pi_C = 2$
1000μF	$\pi_C = 3$

π_q = INFLUENCE OF QUALIFICATION

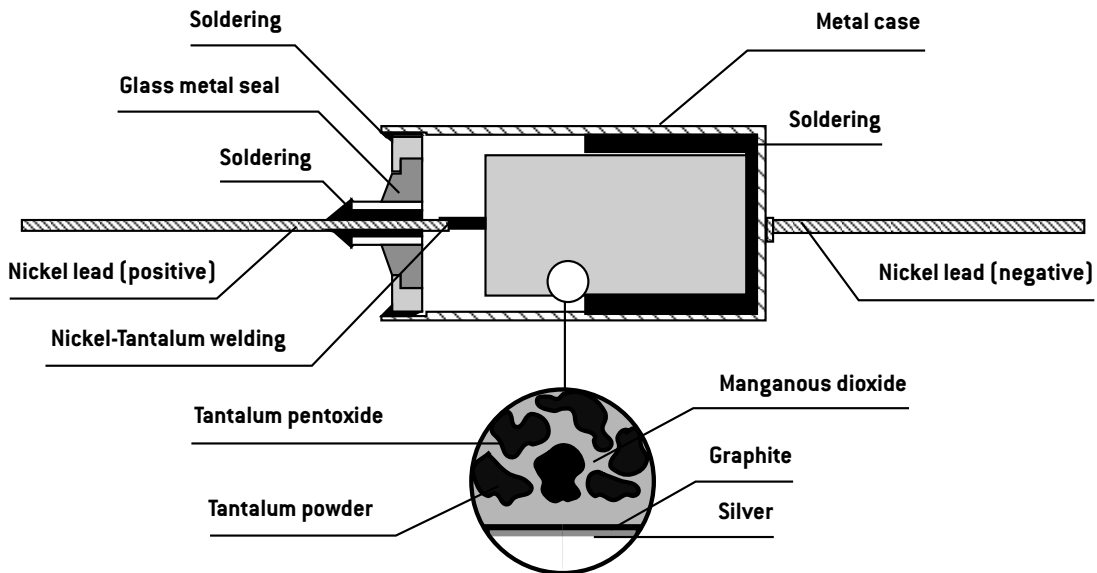|	
Products approved to CECC	$\pi_q = 1$
Others products	$\pi_q = 1$

Axial leads - General characteristics

Applicable for types see below:

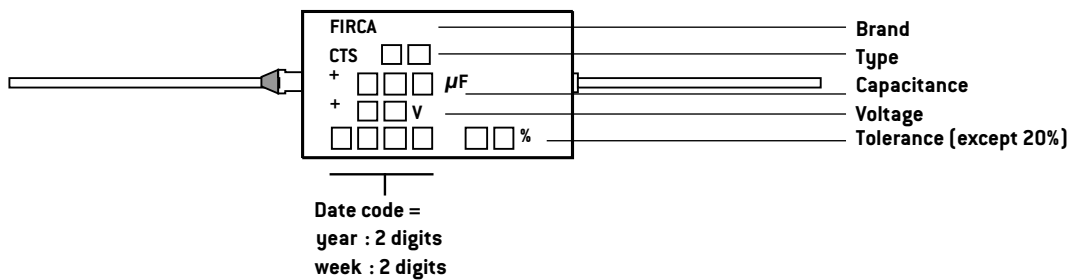**General purpose:** CTS1, CTS13, CTS32, CTS1M
Extended ranges: CTS23, CTS33
Special for power supplies and converters: CTS21, CTS21E

CONSTRUCTION
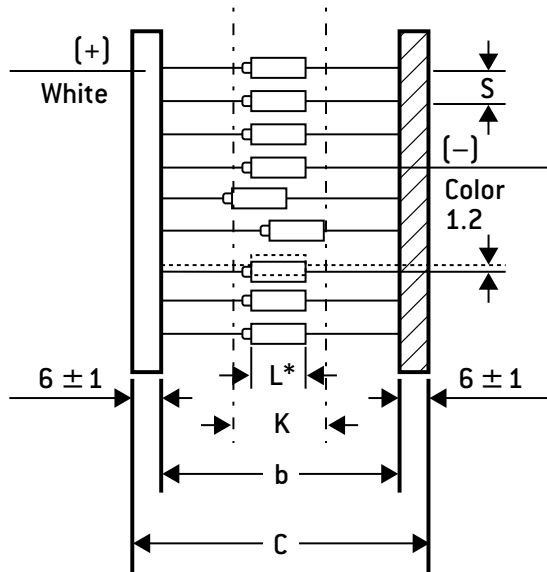

MARKING

PACKAGING

Depending upon the quantities, there will be different types for packaging:

- Loose in plastic bags or boxes
- Taped in plastic bags
- Taped on reel

Dimensions about taping and reels are given on the next page.

Axial leads - Tape & Reel Packaging

LENGTH OF THE CAPACITOR

TAPE DIMENSIONS (in mm)

Case code	L max.	K max.	* b ± 2	C max.	** S ± 0,5	Qty per reel Std/max.
A	8,1	9,5	53	70	5	3500
B	12,8	14,2	53	70	5	2500
C	18,2	18,2	73	90	10	500
D	20,8	20,8	73	90	10	400

* The size b of 53 mm for B case is the standard dimension.

** Max. cumulative tolerance on 10 capacitors: ± 2 mm

REEL SIZE (in mm)
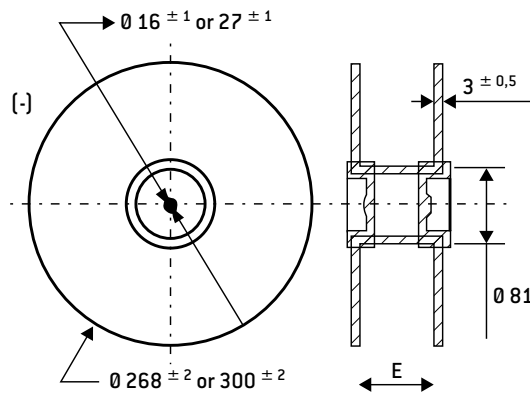
Size E of reels according to case sizes.

EA = 67
B = 67
C-D = 87

General information

Tantalum capacitors are, with ceramic, aluminum and film capacitors, one of the most used family.

The manufacturing technology and the constant improvements in tantalum powders allow it to be the capacitor with the highest CV (product capacitance x voltage) per volume, very long life and high reliability.

It has also the following advantages:
- Wide range of capacitance (less than $1\mu F$ to more than $10\,000\mu F$)
- Wide operating temperature range ($-55°C$ to $+200°C$)
- Electrical characteristics stable with temperature
- Low leakage current
- Very low ESR for some types
- Stability after long periods of storage , without any reforming

All these characteristics allow tantalum capacitors to be commonly used either in large volume markets like mobile phones or computers, or in specific High-Rel applications such as space, aerospace and military.

Its main uses are found in the following functions:
- Filtering
- Bypass
- Coupling
- RC time constant
- Energy storage

Tantalum capacitors can be divided into two main families and several sub-families:

Solid tantalum capacitors:
- Solid MnO_2
  - Metal cases
  - Molded cases
  - SMD
- Solid Polymer
  - SMD

Wet tantalum capacitors:
- Silver cases
- Tantalum cases

HOW TO USE THE SELECTION GUIDE

1 - The **Technical Selection Guide** can be used to select a product according to the main technical requirements.

2 - The **Classification according to specification** makes the link between all major standard specifications and the products.

3 - The **Selection Guide** by family has the same classification as in the catalogue. You will find for each type the main features, the approvals and the page number of the technical data sheet.

MANUFACTURING

ANODE AND INSULATOR

Tantalum capacitors are the capacitors which have the highest ratio of capacitance per volume. This is mainly due to the high dielectric coefficient of its insulator and to its large cross-section.

The basic raw material is a high purity (greater than 99,99%) tantalum powder with a very fine granulation, compressed to form a cylinder or a parallelipiped constituting the anode of the capacitor (positive plate).

The pellet is then sintered at high temperature ($1200°C$ to $2200°C$), under high vacuum (10^{-6} Torr), firstly to purify the powder and secondly to obtain a strong mechanical structure by a welding of the particles.

The insulating part is obtained by anodization to a depth of the tantalum surface which forms a tantalum pentoxide film (Ta_2O_5) with a thickness of about 16 angstroms per anodization volt. The dielectric coefficient is between 21 and 27 depending upon the anodization conditions.

WET ELECTROLYTE: CATHODE AND ENCAPSULATION

In this case, the cathode is formed by a sulphuric acid solution. The anodized tantalum pellet is impregnated with this solution and then placed in a silver or tantalum case, into which some equivalent gelled solution have been previously deposited.

The case is then crimped on the internal PTFE gasket to make the sealing. The final steps are welding (CT79), soldering (CT9) or elastomer seal (CT4) depending on the capacitors.

SOLID ELECTROLYTE: CATHODE AND ENCAPSULATION

In this case, the cathode is formed either by managanous dioxide which is a grey semi conductor or by polymer solution.

Solid MnO_2 cathode is obtained by dipping the pellets into a manganous nitrate water solution which impregnates the internal structure; this solution is then decomposed in a high temperature oven to obtain manganous dioxide. This operation is repeated several times. The nature and quality of this semiconductor are important to some of the electrical parameters (especially the serial resistance).

To finish the negative plate, a graphite coating and then a silver coating are deposited on the outside surface of the manganous dioxide or conducting polymer.

The positive nickel lead is welded on the tantalum wire and the negative lead is either soldered for the products with axial leads or glued with a silver epoxy for the SMD range.

BURN-IN - SORTING - INSPECTION

All the products are submitted to a final burn-in, with differing severities depending upon the characteristics of each type (temperature, voltage, duration).

Then follows the sorting, marking and inspection operations. It can be noted that the procedures for these operations are the same for approved and non approved parts (except the periodical tests).

General information

TYPE IDENTIFICATION - ORDERING INFORMATION

THE COMPLETE IDENTIFICATION OF A PRODUCT IS MADE OF

- The type (or model)
- The case size
- The rated capacitance
- The tolerance
- The rated voltage
- If applicable the CECC specification number

THE TYPE

It can be expressed with the commercial description (CTC21E C 33μF 10% 40V) or the **EXXELIA** part number (TS22EC336K040F).
When applicable the CECC specification number should be indicated.

THE CASE SIZE

It is indicated on the technical data sheets in front of each capacitance-voltage value and is generally identified by a letter code . It is important to give this information because there can be, for the same type, a standard range and an extended range in which the same value will be available in two different sizes.

THE RATED CAPACITANCE

It can be expressed:
- Directly in μF (eg: 47μF)
- Coded according to MIL specification, with:
    - 2 digits number for the value
    - A multiplying factor to obtain the capacitance in pF (power of 10)

  Eg: 567 = 56.10^7 pF = 560μF

THE TOLERANCE

It can be expressed directly in % or identified by a code letter:

$\qquad$ M = $\pm$20%
$\qquad$ K = $\pm$10%
$\qquad$ J = $\pm$5%

N.B.: the standard tolerance for tantalum capacitors is 20%; if no tolerance is specified, it would be considered as 20%.

A 20% tolerance means in fact -20% to $+20\%$.

THE RATED VOLTAGE

It is expressed directly in volts (V)

N.B.: 6,3V rated voltage can be coded as 6V.

CECC SPECIFICATIONS

Some of the products which are described in this catalogue are made to a CECC specification; these documents give in detail the following information for each type:

- The climatic, electrical and mechanical characteristics
- The test and inspection procedures
- The sampling methods and levels
- The tests periods

The reference specifications concerning the tantalum capacitors are the following:

CECC 30 000 (NFC 83-100)
Generic specification: fixed capacitors
- Terminology
- Quality Assessment Procedures
- Test and inspection methods

CECC 30 200 (NFC 83-112)
Sectional specification: tantalum capacitors
- Prefered characteristics
- Quality Assessment Procedures
- Test and inspection methods

CECC 30 201 XXX
Detail specifications solid tantalum capacitors
- Detailed characteristics for each type

CECC 30 202 XXX
Detail specifications wet tantalum capacitors
- Detailed characteristics for each type

CECC 30 800 (NFC 83-113)
Sectional specification: tantalum chip capacitors
- Prefered characteristics
- Quality Assessment Procedures
- Test and inspection methods

CECC 30 801 XXX
Detail specifications tantalum chip capacitors
- Detailed characteristics for each type
- The list of all the detail specifications is given in the selection guide, with the corresponding type.

NB: Some of the products refer to specifications which are no longer published.

OTHER SPECIFICATIONS

In addition to CECC approvals, some of the products are qualified to MIL standard M39006/22, M39006/25, DSCC DWG No. 93026 and some others are listed in ESA (European Space Agency) Preferred Parts Lists ESCC EPPL I or II.